Unit: mm

TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT process)

2SC1815

Audio Frequency General Purpose Amplifier Applications Driver Stage Amplifier Applications

• High voltage and high current: VCEO = 50 V (min),

IC = 150 mA (max)

• Excellent hFE linearity: hFE (2) = 100 (typ.)

at $V_{CE} = 6 \text{ V}$, $I_{C} = 150 \text{ mA}$

: $h_{FE} (I_{C} = 0.1 \text{ mA})/h_{FE} (I_{C} = 2 \text{ mA})$

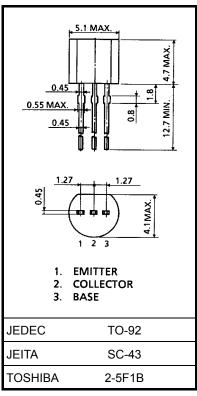
= 0.95 (typ.)

• Low noise: NF = 1dB (typ.) at f = 1 kHz

• Complementary to 2SA1015 (O, Y, GR class)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	60	V
Collector-emitter voltage	V _{CEO}	50	V
Emitter-base voltage	V _{EBO}	5	V
Collector current	IC	150	mA
Base current	ΙΒ	50	mA
Collector power dissipation	PC	400	mW
Junction temperature	Tj	125	°C
Storage temperature range	T _{stg}	-55~125	°C



Weight: 0.21 g (typ.)

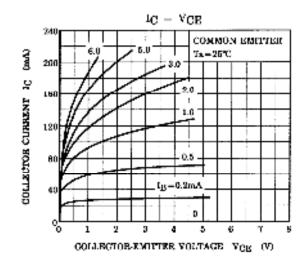
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in

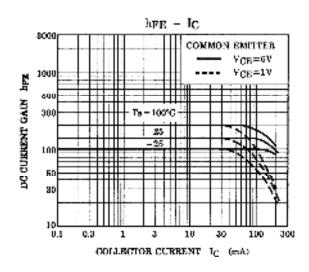
temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

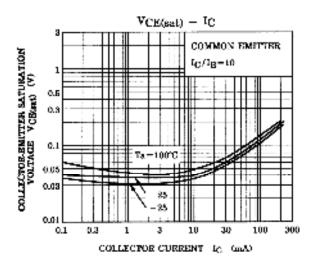
Electrical Characteristics (Ta = 25°C)

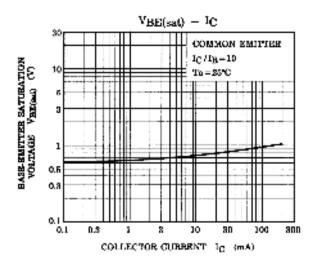
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	V _{CB} = 60 V, I _E = 0	_	_	0.1	μА
Emitter cut-off current	I _{EBO}	V _{EB} = 5 V, I _C = 0	_	_	0.1	μА
DC current gain	h _{FE (1)} (Note)	V _{CE} = 6 V, I _C = 2 mA	70	_	700	
	h _{FE (2)}	V _{CE} = 6 V, I _C = 150 mA	25	100	_	
Collector-emitter saturation voltage	V _{CE (sat)}	$I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$	_	0.1	0.25	V
Base-emitter saturation voltage	V _{BE} (sat)	$I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$	_	_	1.0	V
Transition frequency	f _T	V _{CE} = 10 V, I _C = 1 mA	80	_	_	MHz
Collector output capacitance	C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz	_	2.0	3.5	pF
Base intrinsic resistance	r _{bb'}	$V_{CE} = 10 \text{ V}, I_{E} = -1 \text{ mA}$ f = 30 MHz	_	50	_	Ω
Noise figure	NF	$V_{CE} = 6 \text{ V, } I_C = 0.1 \text{ mA}$ f = 1 kHz, $R_G = 10 \text{ k}\Omega$	_	1.0	10	dB

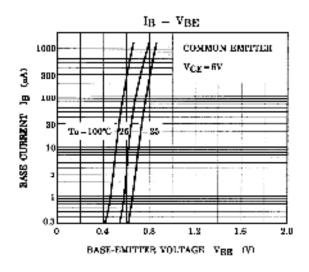
Note: hFE classification O: 70~140, Y: 120~240, GR: 200~400, BL: 350~700

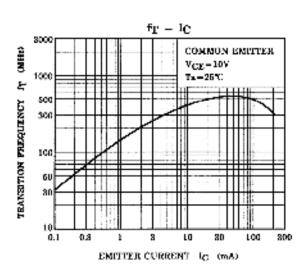


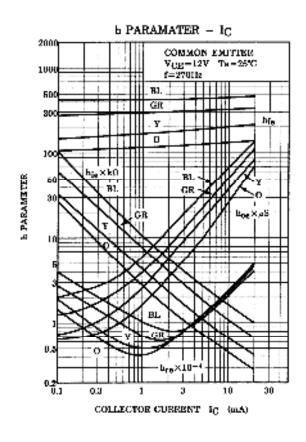


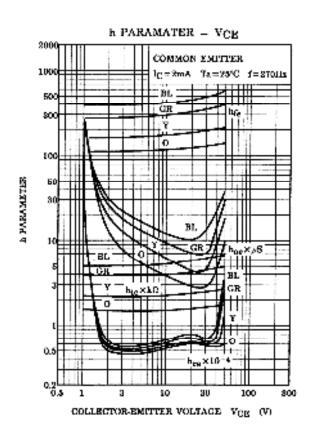


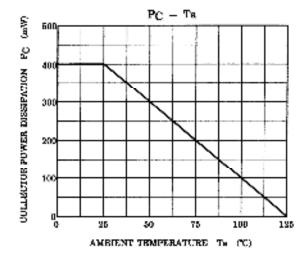












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20070701-EN GENERAL

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